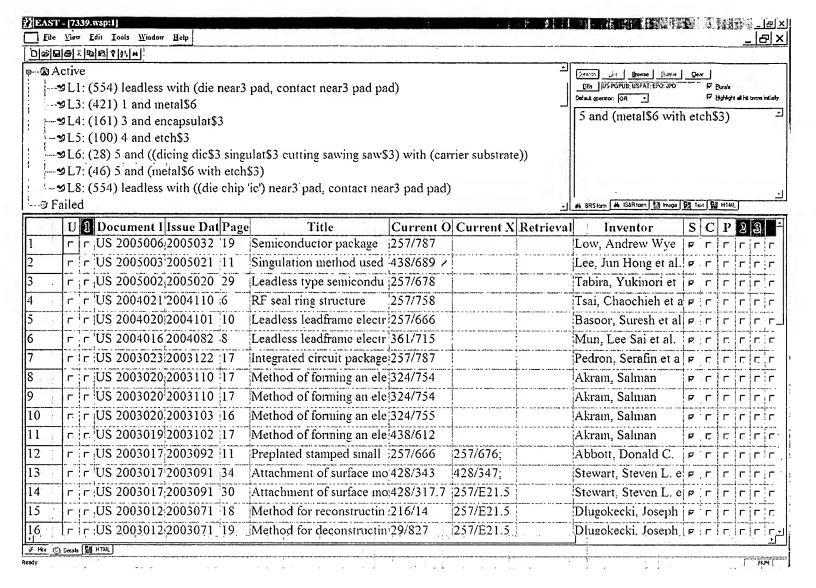
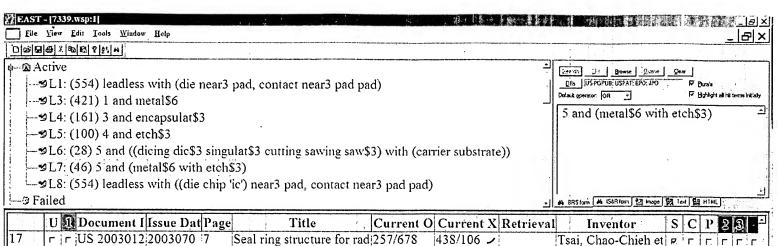
Ref #	Hits	Search Query	DBs	Default Operat	perat s		
L1	554	leadless with (die near3 pad, contact near3 pad pad)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/28 08:22	
L3	421	1 and metal\$6	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/28 07:22	
L4	161	3 and encapsulat\$3	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/28 07:10	
L5	100	4 and etch\$3	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/28 07:10	
L6	28	5 and ((dicing dic\$3 singulat\$3 cutting sawing saw\$3) with (carrier substrate))	US-PGPU B; USPAT; EPO; JPO	OR ON		2005/04/28 07:13	
L7	46	5 and (metal\$6 with etch\$3)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/28 07:22	
L8	554	leadless with ((die chip 'ic') near3 pad, contact near3 pad pad)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/28 08:23	
S1	1	"6821821"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 17:15	
S2	26	"6093584"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 10:02	
S3	1	"6342730".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:00	
S4	1	"6261864".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:01	

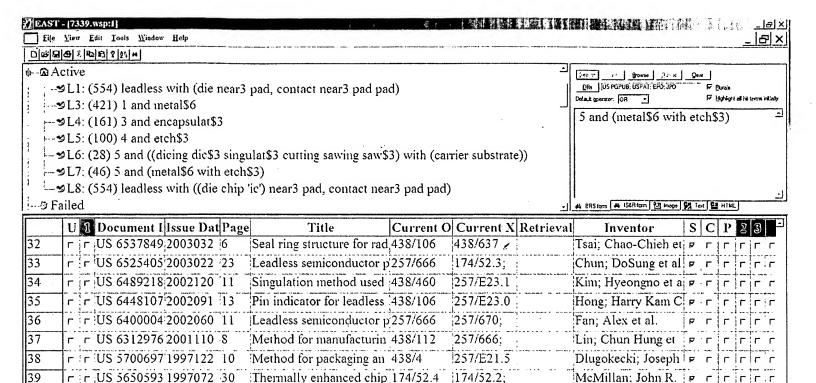
S5	1	"6136681".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:02
S6	1	"6102710".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:02
S7	1	"5474066".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:02
S8	1	"6001671".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:02
S9	4	"6586677"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 10:06
S10	16	"6238952"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 10:19
S11	37	"6081029"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 10:26
S12	49	"5900676"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 15:03
S13	1	"5849608".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:40
S14	1	"5659200".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:40
S15	1	"5554887".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:41
S16	1	"5309429".PN.	USPAT; USOCR	OR	ON	2005/04/27 10:41
S17	2	"6489557"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 10:44
S18	100	"6001671"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 10:44
S19	1	"6762118".PN.	USPAT; USOCR	OR	ON	2005/04/27 12:45

S20	1	"6498099".PN.	USPAT; USOCR	OR	ON	2005/04/27 12:45
S21	1	"6194786".PN.	USPAT; USOCR	OR	ON	2005/04/27 12:46
S22	34	"5457340"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 16:33
S23	100	"6001671"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 16:37
S24	0	"10654240"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/27 17:15
S25	1	"10/654240"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/04/28 07:06





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17	г	r US	2003012	2003070	7	Seal ring structure for rad	257/678	438/106 ~		ao-Chieh et s	1				- r
18	г	r US	2003006	2003040	16	Leadless semiconductor p	257/666	257/676;	Chun, D	oSung et al	7 . [-	r. r	- г	: -
19	Γ.	r US	2002019	2002122	12	SINGULATION METHO	438/460	257/E23.1	Kim, Hye	eongno et a	7 T	-	ГС	- _	T F
20	г	r US	2001001	2001081	17	Leadless plastic chip carri	438/690	257/E23.0	Kwan, K	in Pui et al.	7 [- [гг	Tr	
21	г	r US	2001000	2001071	20	Leadless plastic chip carri	257/692	257/E23.0	McLella	n, Neil et al 🛭	2 · [- [гг	- r	- г.
22	г	r US	6884663	2005042	18	Method for reconstructin	438/126	438/127 /	Dlugoke	cki; Joseph 🕫	ع ا ا	-	r r	: r	- r
23	Г	r US	6882167	2005041	17	Method of forming an ele	324/754	324/765	Akram; S	Salman	2 · [-	r r	- r	7.
24	Γ.	r US	6872661	2005032	16	Leadless plastic chip carri	438/689	438/613 /	Kwan; K	in Pui et al	7 1	-	r. r	- -	- -
25	г	гUS	6831472	2004121	16	Method of forming an ele	324/754	324/765	Akram; S	Salman r	7 . [- [гГ	-	- [-
26	г	r US	6813828	2004110	18	Method for deconstructin	29/827	29/402.01;	Dlugoke	cki; Joseph 🛭	7 1	- [r r	- r	- r
27	г	r. US	6797541	2004092	14	Leadless semiconductor p	438/111	257/E23.0	Chun; D	oSung et al 🛭	7 j f	- [r r	: r	- C
28	г	r US	6773961	2004081	12	Singulation method used	438/112	438/111; /	Lee: Jun	Hong et al.	7 · Γ	-	гг	- -	- -
29	г	r US	6635957	2003102	15	Leadless plastic chip carri	257/691	257/693;	Kwan; K	in Pui et al	7 : F	- 1	ГГ	- _	T F
30	r	r (US	6610924	2003082	9	Semiconductor package	174/52.4	174/52.2;	Lee; Shil	h-Chang et F	ם ר	-	гг	- -	
31	г	r US	6556030	2003042	19	Method of forming an ele	324/754	324/765	Akram; S	Salman F	र ।	-	гг	= c	- [F]
32	jn.	ŗŲS	6537849	2003032	6	Seal ring structure for rad	438/106	438/637	Tsai; Ch	ao-Chieh et s	ا ِ د	-]	r.] r		م



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Pad array semiconductor 257/774

Radiation shielding for in 257/659

Method for packaging an 29/827

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Tape bonding material an 257/672

Leadless chip carrier app 257/691

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Dlugokecki: Joseph 🕫 🕝

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Gilbert; Barry K. et 👂 🕝

Bolger; Justin C.

Butt; Sheldon H.